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# ANOMALOUS STABILITY OF $\nu = 1$ BILAYER QUANTUM HALL STATE

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We have studied the fractional and integer quantum Hall (QH) effects in a high-mobility double-layer two-dimensional electron system. We have compared the "stability" of the QH state in balanced and unbalanced double quantum wells. The behavior of the  $\nu=1$  QH state is found to be strikingly different from all others. It is anomalously stable, though all other states decay, as the electron density is made unbalanced between the two quantum wells. We interpret the peculiar features of the  $\nu=1$  state as consequences of the interlayer quantum coherence developed spontaneously on the basis of the composite-boson picture. © 1997 Elsevier Science Ltd

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### 1. INTRODUCTION

The bilayer quantum Hall (QH) system possesses a rich phase diagram [1] since it allows three controllable parameters, the magnetic length  $l_B$ , the interlayer distance d and the symmetric-antisymmetric tunneling gap energy  $\Delta_{SAS}$ . By controlling these parameters we can realize various bilayer QH states  $\Psi_{m_l m_b m}$  with  $m_{\alpha}$  odd integers and m an integer  $(m_{\alpha} \ge m)$  [2]. When the interlayer and intralayer Coulomb interactions become nearly equal, the  $\Psi_{mmm}$  state is realized at  $\nu \equiv 1/m$ . A novel interlayer quantum coherence (IQC) has been predicted to develop spontaneously in the  $\Psi_{mmm}$  states [3], which is characterized by a pseudo-gapless mode describing the interlayer phase and the electron density difference. A typical QH state is given by  $\Psi_{111}$  at  $\nu = 1$ . The  $\nu = 1/m$  QH state is intriguing since there are two distinguishable states, the monolayer state stabilized by the tunneling interaction and the coherent state  $\Psi_{mmm}$ stabilized by the Coulomb interaction.

We wish to address what are the signals for the spontaneous development of IQC characterizing the  $\Psi_{mnnm}$  state. Murphy *et al.* [4] made an experiment in which they observed an anomalous activation energy

dependence of the  $\nu=1$  state on the tilted magnetic field, which is probably one of the signals [5, 6]. Furthermore, their data indicate that IQC is observable even at a large tunneling interaction,  $\Delta_{SAS}\approx 8.4$  K.

In search for a clear signal we have performed an experiment on bilayer QH states by varying the density ratio of the two layers as well as the total electron density. We hereafter refer to the QH as "balanced QH states" when the densities are equal and as "unbalanced QH states" when they are not equal. Experiments have so far been made extensively on balanced QH states [2, 7] and only limited work has been done on the unbalanced QH states [8, 9]. The study of unbalanced QH states reveals its character: for instance, if the QH state is stabilized by the energy gap  $\Delta_{SAS}$ , it decays as the system becomes unbalanced.

In our experimental data, all QH states depend sensitively on the density ratio except the  $\nu=1$  state. They have strong tendency to decay as the electron density between the two quantum wells is made unbalanced.

On the other hand, the behavior of the  $\nu = 1$  state is strikingly different from all others. The  $\nu = 1$  state is stable even if the density ratio is changed, as long as the

total density is less than a critical value. We interpret that this stability of the  $\nu=1$  state is an evidence of the IQC developed spontaneously.

#### 2. EXPERIMENTAL RESULTS

The sample was grown by molecular beam epitaxy on  $(1\,0\,0)$ -oriented GaAs substrate and consists of two modulation-doped 200 Å GaAs quantum wells, separated by  $Al_{0.3}Ga_{0.7}As$  barriers of thickness  $d_B=31\,\text{Å}$ . It has the total density  $2.3\times10^{11}\,\text{cm}^{-2}$  and the mobility  $3.0\times10^5\,\text{cm}^2\,\text{V}^{-1}\text{s}^{-1}$  at 30 mK at zero gate voltage. Measurements were performed with the sample mounted in the mixing chamber of a dilution refrigerator with a base temperature less than 6 mK. The maximum field of our superconducting magnet is  $13.5\,\text{T}$  at  $4.2\,\text{K}$ . Temperature was measured by a  $RuO_2$  resistance set near the sample and calibrated by  $^3\text{He}$  melting pressure thermometer. Standard low-frequency a.c. lock-in techniques were used with currents less than  $100\,\text{nA}$  to avoid heating effects.

Schottky front and back gates were used to change the total carrier density and the density ratio of the two quantum wells. In Fig. 1 the densities  $n_f$  and  $n_b$  of the front and back layers were obtained from Fourier transforms of the low-field (B < 1.3 T) Shubnikov-de Haas (SdH) oscillations and the total density  $n_t$  was obtained from the Hall resistance at low fields. The sum of  $n_f$  and  $n_b$  is in good agreement with  $n_t$  obtained from the Hall resistance. We note the following features: (a) as the front gate voltage  $V_{fg}$  is increased,  $n_f$  rises for gate voltage  $V_{fg} > -0.2$  V and  $V_{fg} < -0.6$  V and  $n_b$  slightly

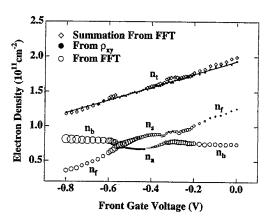


Fig. 1. Carrier density as a function of the front gate voltage. The open circles are the electron densities obtained from Fourier transforms of SdH signals. The total electron densities (solid circles) are measured by the low field Hall resistance. The size of the open circle is proportional to the signal intensity. The open square is the sum of electron densities. The solid curve in the density  $n_a$  is not observed by SdH but is calculated by  $n_a = n_t - n_s$ .

decreases due to a negative compressibility [10]; (b) for the front gate voltage  $-0.6 \text{ V} < V_{fg} < -0.2 \text{ V}$  the electrons are not localized in individual wells but are resonating between them with the averaged densities  $n_s$  and  $n_a$  on the symmetric and antisymmetric states. The maximum density difference at  $V_{fg} = -0.41 \text{ V}$  gives  $\Delta_{SAS} \approx 6.8 \text{ K}$ .

In Fig. 2 we show the magneto- and Hall resistance at  $V_{bg} = -37.2 \text{ V}$  under two typical  $V_{fg}$ . Balanced QH states are seen in Fig. 2(a) at  $V_{fg} = -0.41 \text{ V}$ , where  $n_f/n_b = 1/1$ . Unbalanced QH states are seen in Fig. 2(b) at  $V_{fg} = -0.80 \text{ V}$ , where  $n_f/n_b \approx 1/2$ .

Odd-integer QH states in the inset of Fig. 2(a) are the monolayer states stabilized by the tunneling interaction. It exists only up to a certain magnetic field, beyond which bilayer QH states stabilized by the Coulomb interaction are expected to occur [1]. The  $\nu = 1$  QH state, which is unstable at higher total electron density, has been stabilized at  $n_t = 1.4 \times 10^{11}$  cm<sup>-2</sup>. This property can be understood based on the phase diagram [1]. On the other hand, even integer QH states will be bilayer states made of the same monolayer QH states localized in the two wells, which we call compound states with  $(\nu_f, \nu_b) = (\nu/2, \nu/2)$ , or the monolayer state stabilized by the tunneling interaction. We cannot distinguish them. They are present since these states are robust. The  $\nu = 2/3$  state is the  $\Psi_{330}$  state which is a compound state with  $(\nu_f, \nu_h) = (1/3, 1/3)$ .

In Fig. 2(b) we report the QH effect in the unbalanced configurations obtained by controlling the bias voltages.

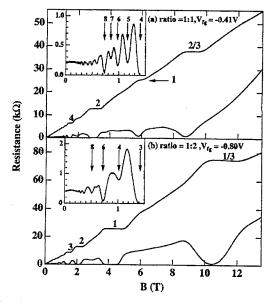


Fig. 2. Magneto and Hall resistance,  $\rho_{xx}$  and  $\rho_{xy}$ , for two typical density ratios  $n_f/n_b$ . The appearance of QH states depends critically on this ratio: (a)  $n_f = n_b = 6.9 \times 10^{10} \text{ cm}^{-2}$ ; (b)  $n_f = 3.4 \times 10^{10} \text{ cm}^{-2}$ ,  $n_b = 7.4 \times 10^{10} \text{ cm}^{-2}$ .

The  $\nu=3$  and 6 states are compound states with  $(\nu_f, \nu_b)=(1,2)$  and (2, 4), respectively, where  $\nu=\nu_f+\nu_b$  and  $\nu_f/\nu_b=n_f/n_b$ . The  $\nu=4$  and 8 states are the "tails" of the compound states with  $(\nu_f, \nu_b)=(1,3)$  and (2,6) broaden by disorder in the sample, because the plateau became wider as the system approached  $n_b/n_f=1/3$ . The origin of the  $\nu=1$  and 1/3 state is discussed in the following stage.

In Fig. 3 we give the Hall resistance measured at fixed  $V_{bg} = -37.2$  V and various  $V_{fg}$ . It is customary to discuss the stability of the QH states by the value of the magnetoresistance  $(\rho_{xx})$ . We propose to discuss the stability in terms of the width of the Hall plateau. We have defined the width of the Hall plateau by the width of the magnetic field within the  $\pm 2.5\%$  range of the Hall resistance after subtracting the classical Hall resistance, as illustrated in Fig. 4.

As is seen in Fig. 5, the plateau widths of the  $\nu=2$  and 2/3 state are widest when  $n_f/n_b=1$  and decrease monotonically as it deviates from the balanced point. This is explained by considering that the  $\nu=2$  and 2/3 states are compound states with  $(\nu_f,\nu_b)=(1,1)$  and (1/3,1/3), respectively. The  $\nu=2$  data show an increase below -0.7 V and reach a maximum at -0.8 V which is the edge of our experimental region. We interpret it as a tail of the monolayer state with  $(\nu_f,\nu_b)=(0,2)$ . In the figure the behavior of the  $\nu=1$  QH state is strikingly different from all the other states. The state is stable over a wide range of density ratio and at the same time no peak is observed at the balanced point. The QH state would be stablest at the balance point if it were stabilized by either  $\Delta_{SAS}$  or any simple correlations.

In Fig. 6 the width of the Hall plateau of the  $\nu = 1$  state is given as a function of  $n_t$  for four different back

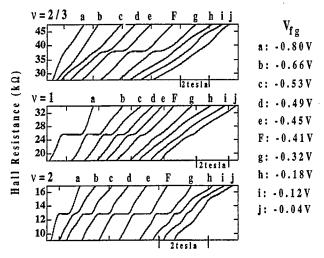


Fig. 3. The Hall resistances near the plateau of  $\nu=2/3, 1$  and 2 QH state are shown at various  $V_{fg}$ . The curve F represents balanced QH effect.

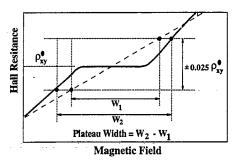


Fig. 4. The definition of the Hall plateau width. The dotted line represents a classical Hall resistance and  $\rho_{xy}^0$  is a quantized Hall resistance.

gate voltage  $V_{bg}$ . It is seen that the plateau width depends on the total density  $n_t$  but not on the density ratio, suggesting an interesting scaling law. The stability decreases as  $n_t$  increases and the QH state becomes unstable when  $n_t \approx 1.7 \times 10^{11} \text{ cm}^{-2}$ . As the density increases beyond  $1.7 \times 10^{11} \text{ cm}^{-2}$ , the  $\nu = 1$  state becomes stable again. This increase is probably due to the tail of the compound state with  $(\nu_f, \nu_b) = (2/3, 1/3)$  having the peak at  $n_f/n_b = 2/1$ .

## 3. INTERLAYER QUANTUM COHERENCE

In this section we discuss the origin of the peculiar property of the  $\nu=1$  QH state. We relate it to IQC based on the composite-boson picture [3, 5, 11].

In the bilayer system the Hamiltonian H is the sum of the kinetic term  $H_K$ , the Coulomb term  $H_C$  and the tunneling term  $H_T$ . (For simplicity we freeze the spin degree of freedom.) The Coulomb term may be written as a sum of two terms [11],  $H_C = H_C^+ + H_C^-$ , where  $H_C^+$  depends only on the total electron density  $n_t$  while  $H_C^-$  depends only on the density difference  $n_f - n_b$ . The term  $H_C^-$  describes the capacitance energy stored between the two layers. The key behavior is that  $H_C^- \to 0$  as  $d/l_B \to 0$  and  $H_C^- \to H_C^+$  as  $d/l_B \to \infty$ . The system has a rich phase diagram depending on relative strength of these

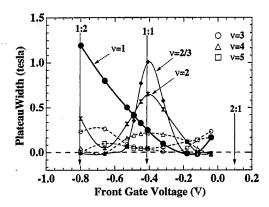


Fig. 5. The Hall plateau width as a function of the front gate voltage  $V_{fg}$ . The curved lines interpolate data points.

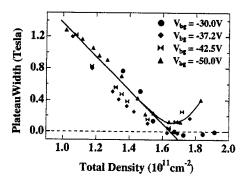


Fig. 6. Stability of  $\nu=1$  as a function of the total density. The dependence of the Hall plateau width on the total density is given for four different back gate voltage  $V_{bg}$ . Almost all data points are on a straight line below the density  $1.6 \times 10^{11}$  cm<sup>-2</sup> and deviate from it by the tail of the  $(\nu_f, \nu_b) = (2/3, 1/3)$  state.

interaction terms. We expect to have the following three phases (A)-(C).

When the capacitance term  $H_C$  is negligible, the bilayer system is mapped exactly to a monolayer system with the spin degree of freedom, where the tunneling term is mapped to the Zeeman term [6, 11]. Therefore, we have two phases: (A) For a large  $\Delta_{SAS}$ , the bilayer QH state is reduced to a "monolayer" QH state built on the symmetric or antisymmetric state. It is clear that the density ratio is fixed as  $n_f/n_b=1$  for the state to realize. (B) For a small  $\Delta_{SAS}$  it is considered as a QH ferromagnet [6, 11] identified with the  $\Psi_{mmm}$  state, about which we explain soon.

The capacitance term  $H_C^-$  acts to break these phases, yielding a new phase (C) described by the  $\Psi_{m_j m_b m}$  state with  $m_f m_b \neq m^2$ . This phase realizes [3] at

$$\nu = \frac{m_f + m_b - 2m}{m_f m_b - m^2},\tag{1}$$

where the density ratio is fixed as

$$\frac{n_f}{n_b} = \frac{m_b - m}{m_f - m}. (2)$$

A special limit with m=0 corresponds to the compound state with  $(\nu_f, \nu_b) = (1/m_f, 1/m_b)$ . It should be emphasized that the QH state exists only at a fixed density ratio in phases (A) and (C).

We now explain why phase (B) is peculiar. The nature of the QH ferromagnet is most easily revealed based on the composite-boson picture. The composite-boson field is defined with the aid of the Chern-Simons (CS) field. We first neglect the terms  $H_C^+$  and  $H_T^-$  in the Hamiltonian. Since the term  $H_C^+$  does not discriminate electrons belonging to different layers, only one CS field C is introduced. The CS flux is attached to each electron and determined by

$$rot C = mn_t \phi_0, \tag{3}$$

in terms of the total density  $n_t$  and the Dirac flux unit  $\phi_0 = 2\pi\hbar c/e$ . Bose condensation occurs when the external magnetic field is cancelled by the CS field,  $C + A^{ext} = 0$ . The constraint (3) dictates that this is only possible at the filling factor

$$\nu = \frac{1}{m}.\tag{4}$$

The essential point is that the density ratio  $n_f/n_b$  is arbitrary. Namely, we obtain degenerate ground states  $|\Delta n\rangle$  with arbitrary density difference  $\Delta n = n_f - n_b$ . The interlayer phase  $\theta$  is the variable conjugate to  $\Delta n$ . The coherent states read

$$|\Psi(\theta)\rangle = \sum_{\Delta n} e^{-i\theta\Delta n} |\Delta n\rangle. \tag{5}$$

The coherent mode is a Goldstone mode. Although the degeneracy is removed by the capacitative term  $H_{\overline{c}}$  and the tunneling term  $H_T$ , there are states having various density difference  $\Delta n$  and hence the coherent states (5) persist. The coherent mode is made gapful and called a pseudo-Goldstone mode. Various IQC phenomena are expected to occur on these states [3, 5, 6, 11].

As we have explained, the condition for the emergence of IQC is the existence of QH states with arbitrary density difference  $\Delta n$ . In our data only the  $\nu = 1$  QH state has a peculiar feature that it continues to exist over a wide range of  $\Delta n$ . Another characteristic feature of the  $\nu = 1$  QH state is that the stability depends only on the total density and not on the density difference. This is naturally explained in the composite-boson picture. Since the  $\Psi_{111}$  state is considered as an integer QH state made of electrons disregarding their layer dependence as in equation (3), the stability should not depend on the density difference. Furthermore, as the density becomes larger, the magnetic length  $l_B$  becomes smaller. Since the ratio  $d/l_B$  becomes larger, the interlayer Coulomb interaction becomes effectively smaller. It acts to break the  $\Psi_{111}$  state. Hence, the stability decreases as the total density increases and the QH state breaks down eventually at a critical density.

In conclusion the best signal for the emergence of IQC is the existence of QH states  $|\Delta n\rangle$  with various density difference  $\Delta n$ . We have observed these QH states in unbalanced double quantum wells by applying bias voltages to the system.

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